

Standard Rectifier Module

$V_{RRM} = 2 \times 1600 \text{ V}$

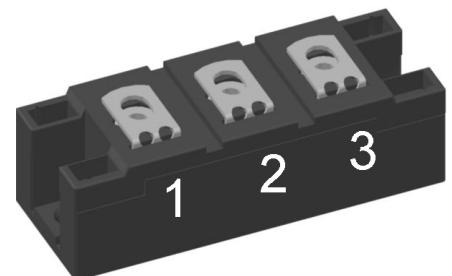
$I_{FAV} = 224 \text{ A}$

$V_F = 1.07 \text{ V}$

Phase leg

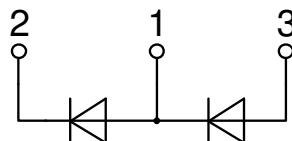
Part number

MDD200-16N1



Backside: isolated

E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: Y4

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Terms .Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

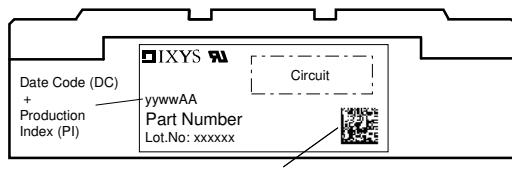
- to perform joint risk and quality assessments;
- the conclusion of quality agreements;
- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

Rectifier

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1700	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1600	V
I_R	reverse current	$V_R = 1600 \text{ V}$ $V_R = 1600 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1 20	mA
V_F	forward voltage drop	$I_F = 300 \text{ A}$ $I_F = 600 \text{ A}$ $I_F = 300 \text{ A}$ $I_F = 600 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1.16 1.39 1.07 1.36	V
I_{FAV}	average forward current	$T_C = 100^\circ\text{C}$	$T_{VJ} = 150^\circ\text{C}$		224	A
$I_{F(RMS)}$	RMS forward current	180° sine	$d = 0.5$		350	A
V_{F0} r_F	threshold voltage slope resistance	} for power loss calculation only		$T_{VJ} = 150^\circ\text{C}$	0.80 0.6	V mΩ
R_{thJC}	thermal resistance junction to case				0.13	K/W
R_{thCH}	thermal resistance case to heatsink			0.08		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		960	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0 \text{ V}$		10.5 11.3	kA
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 150^\circ\text{C}$ $V_R = 0 \text{ V}$		8.93 9.64	kA
I^2t	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0 \text{ V}$		551.3 535.0	kA²s
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 150^\circ\text{C}$ $V_R = 0 \text{ V}$		398.3 386.6	kA²s
C_J	junction capacitance	$V_R = 1100 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	230		pF

Package Y4

Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	<i>RMS current</i>	per terminal			300	A
T_{VJ}	<i>virtual junction temperature</i>		-40		150	°C
T_{op}	<i>operation temperature</i>		-40		125	°C
T_{stg}	<i>storage temperature</i>		-40		125	°C
Weight				150		g
M_D	<i>mounting torque</i>		2.25		2.75	Nm
M_T	<i>terminal torque</i>		4.5		5.5	Nm
$d_{Spp/App}$	<i>creepage distance on surface / striking distance through air</i>		<i>terminal to terminal</i>	14.0	10.0	mm
$d_{Spb/Abp}$			<i>terminal to backside</i>	16.0	16.0	mm
V_{ISOL}	<i>isolation voltage</i>	$t = 1$ second $t = 1$ minute 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		3600		V
				3000		V

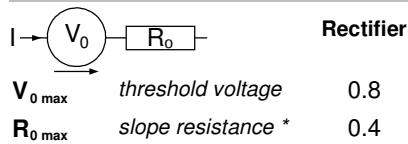


Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDD200-16N1	MDD200-16N1	Box	6	500212

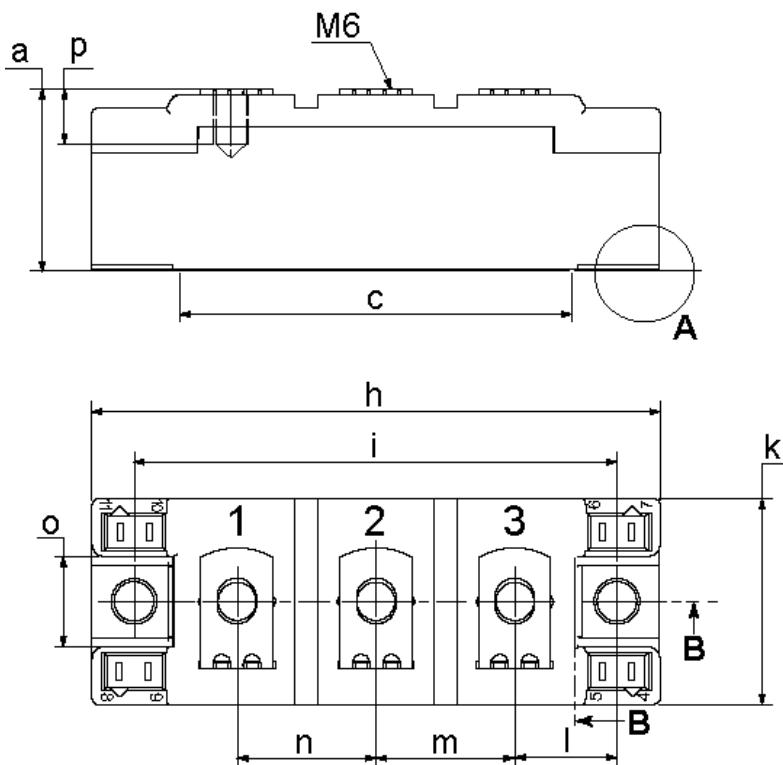
Equivalent Circuits for Simulation

* on die level

 $T_{VJ} = 150$ °C

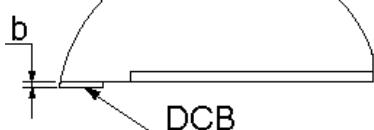
$V_{0\max}$ threshold voltage 0.8 V
 $R_{0\max}$ slope resistance * 0.4 mΩ

Outlines Y4

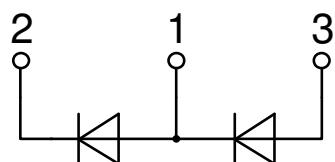
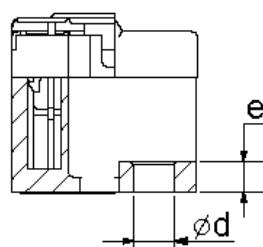


Dim.	MIN [mm]	MAX [mm]	MIN [inch]	MAX [inch]
a	30.0	30.6	1.181	1.205
b	typ. 0.25		typ. 0.010	
c	64.0	65.0	2.520	2.559
d	6.5	7.0	0.256	0.275
e	4.9	5.1	0.193	0.201
h	93.5	94.5	3.681	3.720
i	79.5	80.5	3.130	3.169
k	33.4	34.0	1.315	1.339
l	16.7	17.3	0.657	0.681
m	22.7	23.3	0.894	0.917
n	22.7	23.3	0.894	0.917
o	14.0	15.0	0.551	0.591
p	typ. 10.5		typ. 0.413	

A (3:1)



B-B (1:1)



Rectifier

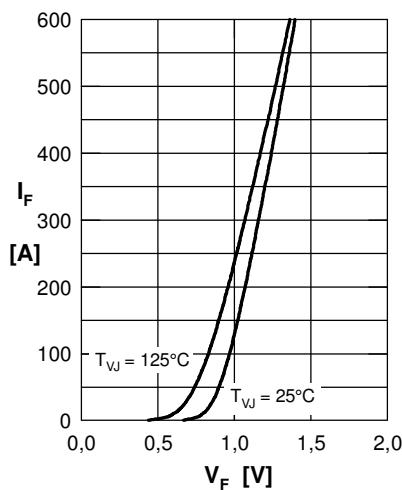


Fig. 1 Forward current versus voltage drop

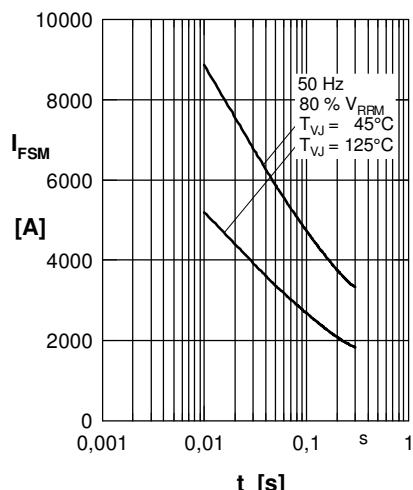
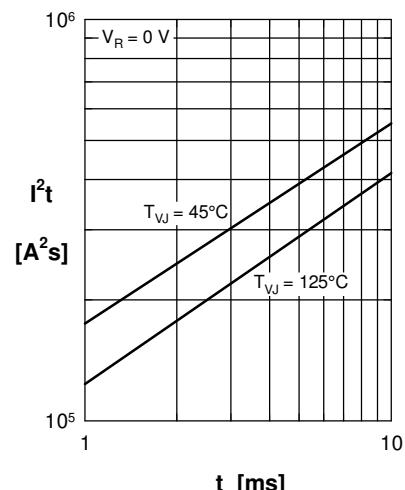
Fig. 2 Surge overload current
I_FSM: Crest value, t: duration

Fig. 3 I^2t versus time (1-10 ms)

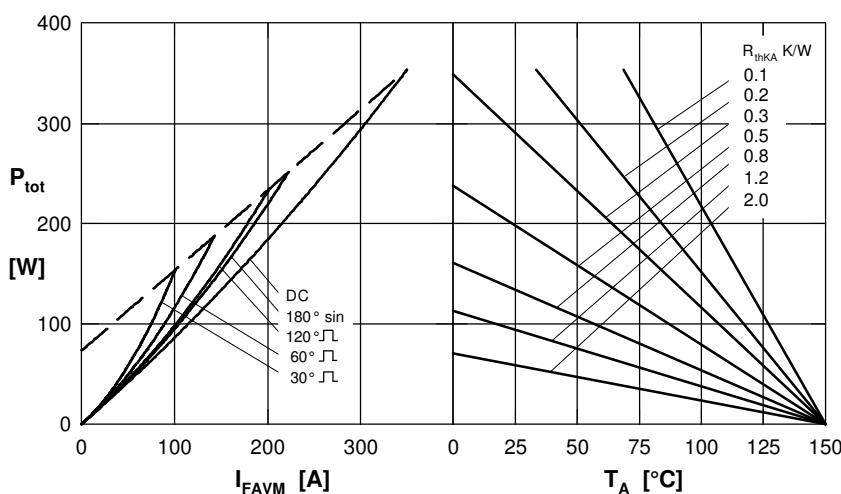


Fig. 4 Power dissipation versus forward current and ambient temperature (per diode)

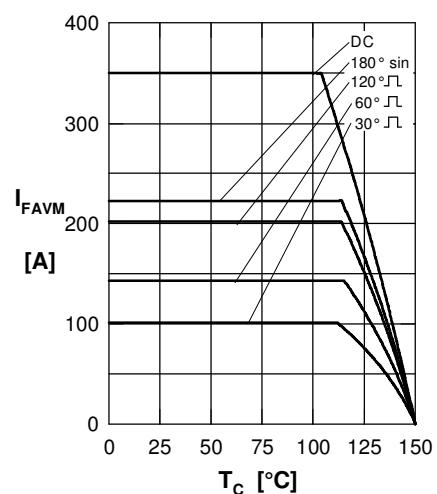


Fig. 5 Maximum forward current at case temperature

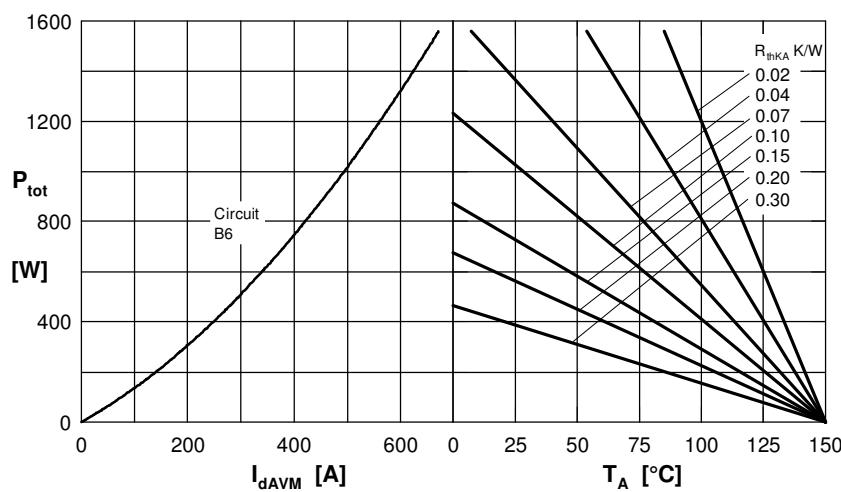


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

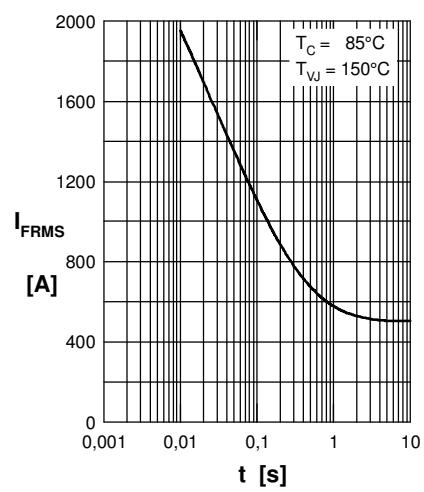
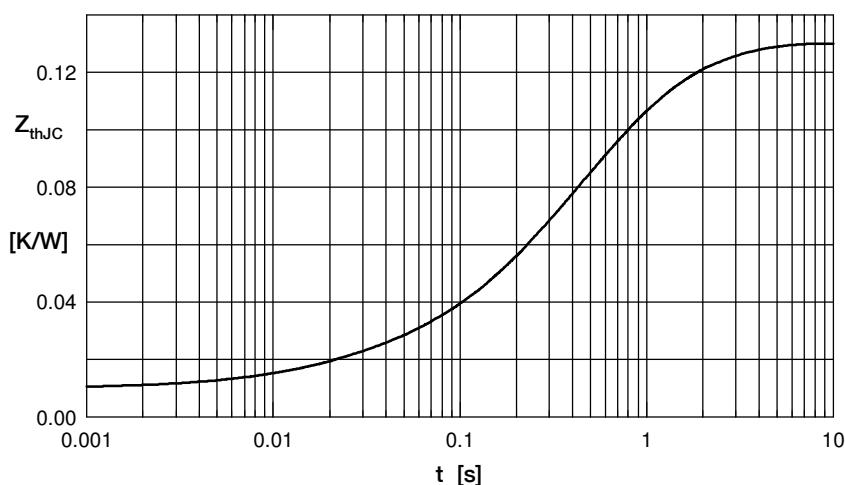


Fig. 7 Rated RMS current versus time (360° conduction)

Rectifier



Constants for Z_{thJC} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.0100	0.00014
2	0.0065	0.019
3	0.0250	0.180
4	0.0615	0.520
5	0.0270	1.600

Fig. 8 Transient thermal impedance junction to case